The given differential equation

$$\frac{3d^2y}{dt^2} + 4\left(\frac{dy}{dt}\right)^3 + y^2 + 2 = x$$

Order of differential equation

= highest derivative present in the differential equation

= 2

Degree is the maximum power of highest derivative.

Here degree = 1.

Hence there is no atternative correct out of the given obcides.

 (C) Fourier series is defined for a periodic function only. Here in atternative (C) term e⁻¹¹¹ makes a non-periodic function.

Hence alternative (C) is the correct choice

- 3. (0) Probability of an odd number = $\frac{N(E)}{N(S)} = \frac{3}{6} = \frac{1}{2}$
 - Probability of an even number = $\frac{N(E)}{N(R)} = \frac{3}{6} = \frac{1}{2}$

since both the events are independent, therefore

$$P(odd/oven) = \frac{1}{2} \times \frac{1}{2} = \frac{1}{4}$$

.

4. (B) Given differential equation

$$\frac{d^2 y}{dx^2} = 5 \frac{d y}{d x} + 6 y = 0$$

: Auxiliary equation is

$$D^2 - SD + 6 = 0$$

 $(D - 2) (D - 3) = 0$
 $D = 2$

 (A) Even and odd perts of a unit-step function w(f) can be given by



We know that

1710

$$u(t) = \begin{cases} 1 & \text{for } t \ge 0 \\ 0 & \text{for } t \ge 0 \end{cases}$$

$$u(t-0) = \begin{cases} 1 & \text{for } t \ge 0 \\ 0 & \text{for } t \ge 0 \end{cases}$$

$$\frac{u(t) + u(-0)}{2} = \begin{bmatrix} \frac{1}{2} & \text{for } t \le 0 \\ \frac{1}{2} & \text{for } t \ge 0 \\ 0 & \text{for } t \ge 0 \end{cases}$$

so, Even part of $u(t) = \frac{1}{2}$

8. (C) Given
$$x(n) = \left(\frac{5}{6}\right)^n w(n) - \left(\frac{6}{5}\right)^n w(-n-1)$$

Hare in the given signal x (n) first sequence is causal sequence while the second sequence is non-causal sequence.

$$a^{\alpha}u(n) \stackrel{Z}{\longleftrightarrow} \frac{Z}{Z-\theta} : |Z|^{2}|1$$

 $n \qquad \left(\frac{5}{6}\right)^{\alpha}u(n) \stackrel{Z}{\longleftrightarrow} \frac{Z}{Z-\theta} : |Z|^{2}|5$

$$\begin{array}{ll} \text{If} & a^{6} \, w(-n-1) \stackrel{Z}{\longleftrightarrow} - \frac{Z}{Z-0}; \, \| \, Z \,\| < \| \, a \,\| \\ \text{then} & \left(\frac{6}{5} \right)^{6} \, w(-n-1) \stackrel{Z}{\longleftrightarrow} \frac{Z}{Z-\frac{5}{6}}; \, \| \, Z \,\| > \frac{6}{5} \end{array}$$

Hence, region of convergence of the sequence x(n) must be $\frac{5}{n} < |x| < \frac{6}{n}$.



from figure

$$\begin{split} \gamma(t) &= \frac{1}{C} \int i \, dt \\ \gamma(t) &= \frac{1}{C_F} i(t) \\ I(0) &= \frac{1}{C_F} i(t) \\ n &= \frac{1}{C_F} \frac{1}{C_F} \frac{1}{C_F} \\ &= \frac{1}{c} \left(R + L + \frac{1}{C_F} \right) \quad [\cdot \cdot L \langle V(t) \rangle = \frac{1}{C_F}] \\ \gamma(t) &= \frac{1}{C_F} \frac{1}{C_F} \frac{1}{R_{C_F} + 1} \end{split}$$

NOW,

$$e \qquad Y(s) = \frac{\frac{1}{1c}}{s^2 + \frac{R}{1}s}$$

On comparing A.E. $s^2 + \frac{R}{L}s + \frac{1}{LC} = 0$ with standard equation

$$s^2 + 2\xi n_y s + n_y^2 = 0,$$

we get $2\xi n_y = \frac{B}{L}$

$$\omega_e^2 = \frac{1}{LC}$$

 $\omega_e = \frac{1}{\sqrt{LC}}$

$$\xi = \frac{R}{2\alpha_0 L} = \frac{R}{2} \sqrt{\frac{C}{L}}$$

for no oscillations, ξ ≥ 1

or
$$\frac{R}{2}\sqrt{\frac{C}{L}} \ge 1$$

 $R \ge 2\sqrt{\frac{L}{L}}$

(B) ABCD parameters is represented by relation

$$v_1 \underbrace{\uparrow}_{n : 1}^{l_1} \underbrace{\downarrow}_{n : 1}^{l_2} v_2$$

$$\begin{bmatrix} V_1 \\ I_1 \end{bmatrix} = \begin{bmatrix} A & B \\ C & D \end{bmatrix} \begin{bmatrix} V_2 \\ I_2 \end{bmatrix}$$

from given figure, we have turns ratio, i.e.

$$\frac{V_1}{V_2} = \frac{I_2}{I_1} \frac{N_1}{N_2} = \alpha$$
 ...(0)

from relation (i) and (ii)

$$I_1 = CV_2 * DI_2$$

 $D = X = \frac{I_2}{I_2} \Big|_{V_2 = 0} = \frac{1}{n} \quad \left(\frac{1}{1} \frac{I_2}{I_1} * n \right)$

9. (B) Given R = 2kG

$$C = \frac{1}{400} \mu F$$

resonant frequency is series RLC circuit is given by

$$f_{c} = \frac{1}{2\pi \sqrt{LC}} - \frac{1}{2\pi \sqrt{1 \times \frac{10^{-6}}{400}}} - \frac{1}{\pi \times 10^{4} \text{ Hz}}$$

 (C) According to maximum power transfer theorem, the maximum power will transfer to the load when R_B = R_L = 100Ω (Here) and it is given by



11. (C) Refer synopsis.

12. (B) Temperature dependency of reverse saturation current is given by relation

$$l_{0}(T) = l_{0}2^{\frac{(T-T_{0})}{10}}$$

where, Is (T) = saturation current at temp. T

$$I_0 = ?$$

 $\frac{40-20}{10} = 10 \times 2^2 = 400 \text{Å}.$

- (C) The primary reason for the widespread use of silicon in semiconductor device technology is the favourable properties of allicon-dioxide (BIO₁).
- (C) A current shurt feedback in an amplifier is used to decrease the input resistance and to increase the output resistance.







- 17. (B) The cascade amplifier is a multistage configuration of 21. (A) Given $x(n) = \left(\frac{1}{2}\right)^n u(n)$

	2
16	43
	32
	$11 \rightarrow B$

$$(43)_{10} = (28)_{10}$$

- (43) = 01000011 (BCD system)
- Let the output from block 1 as shown below is y.



Since 1 input is not given in block-2. So it cannot be sched further due to data insufficiency

(8) From the given options alternative (8) is the correct choice. Since the cansal system has non-zero value for (2 0 only.



(D)

 $y(0) = \left(\frac{1}{4}\right)^n w(0)$ x(e(0) = 1 . (1 + k m(0) A sin (m,t) → Amplitude modulation

 $y(n) = x^2 n = \left(\frac{1}{2}\right)^{2n} u^2(n)$ $y(n) = \left[\left(\frac{1}{2}\right)^2 \right]^n \omega(n)$

- k m(f) A sin (m,l) → D SB-SC modulation
- A sin los. + k m(t) -> phase modulation Asin at+k m(t) dt > Frequency modulation
- 23. (A) The power present in the signal

$$s(l) = 8 \cos \left(20\pi l - \frac{8}{2}\right) + 4 \sin (15\pi l)$$

= $\frac{8^2}{2} + \frac{4^2}{2}$
= 40

- 24. (C) SSB analog modulation scheme requires the minimum transmitted power and minimum channel bandwidth
- 25. (C)
- 26. (D) Lag network is an RC network



$$\begin{array}{c} \begin{array}{c} & T_{k} + \frac{1}{1+|k|} \\ \alpha & T_{k$$

$$\begin{split} & (\Lambda(G)m) & 1 + \frac{1}{\sqrt{2\pi}} \int_{\mathbb{T}} \exp\left(-\frac{\pi}{2}\right)^{2} dx \\ & = \lambda \frac{1}{\sqrt{2\pi}} \int_{\mathbb{T}} \exp\left(-\frac{\pi}{2}\right)^{2} dx \\ & = \lambda \frac{1}{\sqrt{2\pi}} \int_{\mathbb{T}} \exp\left(-\frac{\pi}{2}\right)^{2} dx \\ & \text{is the } x + \frac{1}{\sqrt{2\pi}} \int_{\mathbb{T}} \frac{\pi}{2} \sqrt{\frac{1}{2\pi}} \\ & \text{or } & x + \sqrt{\frac{1}{2\pi}} \int_{\mathbb{T}} \frac{\pi}{2} \sqrt{\frac{1}{2\pi}} \\ & \text{or } & 1 + \frac{1}{2} \sqrt{\frac{1}{2\pi}} \int_{\mathbb{T}} \frac{\pi}{2} \sqrt{\frac{1}{2\pi}} \\ & \frac{1}{2} \sqrt{\frac{1}{2\pi}} \int_{\mathbb{T}} \frac{\pi}{2} \sqrt{\frac{1}{2\pi}} \\ & \text{Tr} \left(\frac{1}{2}\right) - \frac{1}{2\pi} \exp\left(-\frac{\pi}{2} \sqrt{\frac{1}{2\pi}} - \frac{1}{2} \sqrt{\frac{1}{2\pi}} \right) \\ & \text{Now, } & 1 + \frac{\sqrt{\frac{1}{2\pi}}}{\sqrt{2\pi}} - \frac{1}{2} \sqrt{\frac{1}{2\pi}} \\ \end{array}$$

$$\frac{1}{2\sqrt{2\frac{1}{8}}} = \frac{1}{2} = 1$$

(Sincle Gaussian function).

Let the derivative of the symmetric function is y (5).e.

$$y(0) = \frac{g}{dt} \cdot e^{-t^2} = -2t \cdot e^{-t^2}$$

36. (C) Refer synopsis

I = Identity matrix

- (8) (8) Here the instantaneous current (1 (1) is easily
 - calculated by using superposition theorem.



Case 1. When current source 5/0"A is taken while 10 ∠ 60'A is open-circuited. The equivalent circuit becorres as shown in fig. (a)



From figure (a)

Case 2. When current source 10,260'A is taken while 5/20"A is open-circuited. The equivalent circuit becomes es shown in fig. (b).



From figure (b) Now

- - 10,260° 5,20°
 - = 10 cos 60" + J 10 sin 60

$$= \frac{10}{2} + 10 \frac{\sqrt{3}}{2} - 5 - 160$$

= $110 \frac{\sqrt{3}}{2}$
 $\sqrt{3}$

Alternative method :

KCI at note &

$$i_1 = \frac{10\sqrt{3}}{2} \angle -90^{\circ} \text{ amp.}$$

39. (B) From given figure



- Z = L_1 + L_1 + L_2 2M_1 + 2M_1 L. = /50 $L_2 = 720$ $L_3 = /20$
- M. = / 100
- M- = / 10D
 - Z = [j5+j2+j2-2.j10+2.j10]

= 190

(B) Calculation for Ver (Thevenin's voltage)



KCL at Note A

- VA-0 . VA-10 = 1 214 - 3
- $V_A = \frac{15}{2} = 7.6V$
- Van = Va = Vm = 7.5V Calculation for Ren : Ren in the dependent acuros

notwork is the ratio of V where, V is the voltage applied between the open-terminal and I is the current produced by this voltage source provided that all the independent



(C) From fig. reading in the ideal voltamoter



- = 10 $\left(\frac{R}{R+R} \frac{1\cdot 1R}{1\cdot 1R+R}\right)$ 10 (1-11) 42 = = 0.2384
- 42. (D) From the synopsis the standard equation of the h-parameters are

2.	0.0	-
ν,	20	

$$V_1 = h_{11}I_1 + h_{12}V_2$$
 ...(A)

from given figure

V. = 101. + V. Vy = 20 ft. + (.) On comparing equation (i) with equation (A) and equation (ii) with equation (B), we get

$$b_{11} = 10;$$
 $b_{12} = 1$
 $b_{21} = -1;$ $b_{22} = \frac{1}{20} = 0.05$

or
$$\begin{bmatrix} h_{11} & h_{12} \\ h_{21} & h_{22} \end{bmatrix} = \begin{bmatrix} 10 & 1 \\ -1 & 0.05 \end{bmatrix}$$

43. (B) The given C-R circuit is a HPF (high pass filter) acts as a differentiator



Thus, we get the same magnitude output but opposite polarity.

44. (B) Give No for sample A = 1019 atoms/om3 = p Na for sample B = 1018 atoms/cm8 = o

$$\begin{array}{rcl} & & & & \\ & & & & \\ \mu_{\mu} & & & \\ \mu_{\mu} & & \\ \sigma_{\mu} & = & n \sigma_{\mu} \mu_{\mu} \\ d & & \sigma_{\mu} & = & \rho \sigma_{\mu} \mu_{\mu} \\ d & & \sigma_{\mu} & = & \frac{\rho_{\mu} \mu_{\mu}}{10^{10} \times 1} = \frac{10^{10} \times 1}{10^{10} \times 3} = \frac{3}{3} \end{array}$$

45. (B) Given

$$d = 10\mu m = 10 \times 10^{-10} m$$

 $a_1 = 11.7$
 $a_2 = 8.85 \times 10^{-12} Film$
 $\frac{G}{A} = 7$

We know that

$$C = \frac{d_{2} \alpha_{1}}{d}$$

$$\frac{C}{A} = \frac{d_{1} \alpha_{2}}{d}$$
(depletion capacitance of the diode per square metre)
= 845 × 10⁻¹⁰ × 11-7



Since here base and emitter are shorted to each other, therefore, the given circuit will work as a clode.

The diode current is given by relation

$$\begin{split} I &= I_0 \left(e^{\frac{2\pi V - 1}{V}} \right) \\ &= I_0^{-12} \left(e^{\frac{2\pi V - 1}{V}} - 1 \right) \quad [: V = V_{BC} = 0.7 \text{ V}] \\ &= I_0^{-12} e^{4602 \times 10^{11}} - 1 \end{split}$$

47. (C) From given figure



RIR (AIMGIR=1MG

Since R. + -

Therefore, only input offset ourrent can be measured.

 (A) The given op-amp circuit is a high pass filter and its cut-off frequency in radisec is given by



49. (D) We know that in differential amplifier differential mode calls, ADM is given by



From above expression are conclude that large value of Re decreases the common mode gain only.



Therefore, the device is in saturation region.





Onia			input side, we get
			In Ra + Voc + leRe
	20		In (430k01) + 0.7 + (la + (la) 1kt
10	20-07	*	In (430 + 1 + 50) 103
01	lø.	•	19-3 461 × 10 ¹ amp
or	la la		0-0401 × 10 ⁻³
or			40µA
From	figure, volta	91	across terminal C of the transist
	Vc		$V_{00} = I_0 R_0$
			$20 - \beta i_0 2 \times 10^3$
			$20 - 50 \times 40 \times 10^{-6} \times 2 \times 10^{3}$

We know that







Since output is at logic 0. So transistor is in saturation

Vez	٠	075 V
I _N		Var. 1 RD
		075
		075 m

54. (A)

A	в	C	1
0	0	0	0
0	0	1	0
0	1	0	0
0	1	1	1
1	0	0	0
1	0	1	0
1	0	1	0
1	1	0	1
1	1	1	0

From the A-map of the given function, we get

$$I = B(A+C)(\overline{A}+\overline{C})$$

55. (C) We know that for transletor T_1 and T_2 is given by relation

$$\begin{split} I_{DS}(T_1) &= \frac{1}{2}K_1(V_{OB_1} - V_0)^2 \\ I_{DB}(T_2) &= \frac{1}{2}K_2(V_{OB_2} - V_0)^2 \end{split}$$



$$\begin{array}{ccc} gluon & K_1 = 56 \, \mu A V^2 \\ K_2 = 8 \, \mu A V^2 \\ V_1 = V_1 & V \\ frem grave flaure \\ V_{CS_1} = S - V_0 \\ and & V_{CS_2} = S - V_0 \\ and & V_{CS_2} = V_1 \\ mod & I_{CS} \left(T_1\right) = I_{DS} \left(T_2\right) \\ mod & I_{CS} \left(T_1\right) = I_{DS} \left(V_{CS_2} - T \right) \\ \alpha & \frac{1}{2} \, \Delta S \left(S - V_0 - T\right) = \frac{1}{2} \cdot S \left(V_{CS_2} - T \right) \\ \alpha' & S + 1 \\ mod & S + 1 \\ \alpha' & V_S = 3 \, V_S \\ \alpha' & V_S = 3 \, V_S \end{array}$$

 (C) Given that G_n = 0. The characteristic table of J K F/F as shown below:

J	К	Qcet
0	0	0,
0	1	0
1	0	1
1	1	ā,

from the characteristic table it is clear if J=1 and $\Omega_{\rm m}=0.$ So for any value of K (i.e. either 0 or 1). $\Omega_{\rm pet}$ will be lowin 1

 (A) From the given figure it is clear that it is 3 bit binary rivels down counter.



Since $\overline{\Omega}_{0}$ of FiF T₀ is passed through T₁ and $\overline{\Omega}_{1}$ of T₁ is assessed through T₂.

Hence the next state will be 0 1 0.

a (D) Let CS = 1

'X' can be considered as '0' of '1

In this address A8 and A9 both are in '0' Logic, so both chip will not select, so this address will not select any ohit.

8. (4) Given equation

$$y_{0} = 0.5 \text{ s/}(-\xi_{0} = 0.5 \text{ s/}(-\xi_{0} = 0.5 \text{ s/}(-\xi_{0} = 1) \dots (4)$$

We have that
 $y_{0} = -\xi_{0} = e^{-i\phi T} X ((a), B \text{ graving times shifting property
of $Y(a) = -\xi_{0} = e^{-i\phi T} X ((a), B \text{ graving times shifting property
of $Y(a) = -\xi_{0} = e^{-i\phi T} X ((a), B \text{ graving times shifting property
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of Y(a) = -\xi_{0} = e^{-i\phi T} X ((a), B \text{ graving times shifting property
of Y(a) = -\xi_{0} = e^{-i\phi T} X ((a), B \text{ grav$$$$$$$$$

$$H(\omega) = \frac{1}{X(\omega)} = (1 + \cos \omega T) e^{-\omega}$$

60. (C) Refer synopsis.

- 61. (B) Given the output of the system $\gamma(\alpha) = A X (\alpha - n \delta)$
 - Equation (A) can be written as

$$\forall (\phi^{in}) = A e^{i\phi^{in}} X (\phi^{in})$$

 $H (\phi^{in}) = \frac{Y (\phi^{in})}{X (\phi^{in})} = A e^{i\phi^{in}}$
 $= |H (\phi^{in})| \angle H (\phi^{in})$

$$\angle H(\theta^{in}) = -inf_0$$

or
$$\angle H(\theta_{B}) = -w_{0}u_{0} + Xu_{0}$$

where, k is a arbitrary integer

$$\frac{1}{a} \sigma^{-\beta 2 \theta_{B}^{k} l} x\left(\frac{l}{\sigma}\right)$$

$$x'(t) = \frac{1}{3}x(\frac{t}{3})e^{-\frac{t^{2}t}{3}}$$

63. (B) The closed loop system is stable for



Thus final range of k is

64. (C)



V₀ = ± 10 V as supply voltage = ± 10 V when, V₀ = 10 V



From given figure (a)

$$V^* = \frac{2}{2*0.5} \times 10$$

= 8V

when, $V_0 = -10$ V



Fig. (b)

From figure (b)

$$V^- = \frac{2}{2+2}(-10) = -5V$$

The required hysteresis loop is given in option (B): ((b) Given, r(t) = t (*i.e.* ramp input)

$$R(a) = \frac{1}{a^2}$$

H(a) = 1

We know that steady state error Lim 8 1+G(4) H(4 Um - PH + G (c) Lim s [1+ G (s)] hoe of system = en = 5% = 1/20 = Ke where K_a = Zero frequency gain of the system. (A) Given G (s) = = = = = (s + 3) (A) - + x

Alternative (A) is the correct choice because of the following reasons :

- Open loop poles are stats at K = 0 and terminate either at open loop zero or infinity.
- (ii) A point on the real axis is on locus if the number of open loop poles plus zeros on the real axis to the right of the points is odd. Here alternative (B), (C) and (C) are not satisfied by this condition.

69 (C) In a p-type substrate there is majority of fixed positive clus to the presence of positively charged ions.

This can be better understood by the figure shown beiger '



- of = 90 kHz
 - (- = 5 kHz BW = 7 and device input x (f) and output y (f) is characterized by
 - FM equation is given as

$$x(t) = A \cos[\omega_{e} t + \beta \sin \omega_{ee} t]$$

$$\begin{array}{c} \beta & - \frac{df}{dr} & \frac{\partial \partial \partial \partial \partial e_{0}}{\partial r} = 18 \\ \sigma & & y/\theta + A \cos \left[a_{0}t^{4} + 18 \sin a_{0}t^{4} \right] \\ \sigma & & y/\theta + A^{2} \cos^{2} \left[a_{0}t^{4} + 18 \sin a_{0}t^{4} \right] \\ \sigma & & y/\theta + A^{2} \cos^{2} \left[a_{0}t^{4} + 18 \sin a_{0}t^{4} \right] \\ \sigma & & y/\theta + A^{2} \left[\frac{1}{2} + \frac{1}{2} \cos \left(2a_{0}t^{4} + 36 \sin a_{0}t^{4} \right] \\ \sigma & & y/\theta + \frac{A^{2}}{2} + \frac{A^{2}}{2} \cos \left(2a_{0}t^{4} + 36 \sin a_{0}t^{4} \right] \\ \end{array}$$

The bandwidth of the output signal

$$\beta' = \frac{M}{I_m}$$

M = N.f. (where N = 36 for output signal) Af = 35 × 5 = 18 Therefore, the bandwidth of the output signal by Cardons

nule

71. (A)

From given figure input x (f) can be represented as The implee response of a matchast filter is dalayed version of input. Since delay is not given, so assumed to be zero,

y(0) = x(0 - x(0

where, - represents convolution

$$r(t) = r(t) - 2\cdot 2r(t-1) + 2\cdot 2r(t-2) - 2\cdot 2r(t-3)$$

or w(t) = x(t) - 4r(t-1) - 4r(t-2) - 4r(t-3) + r(t-4)

graphically y (5 is shown below :



(C) Given that noise with uniform power spectral density of N₂ WHz is pessed through a filter H (w) = 2e^{-j} = 6 followed by an ideal low pass filter of bandwidth R Hy / e

$$S_{n}(n) \rightarrow H(n) = Y_{1}$$

 $2e^{\frac{1}{2}H'_{0}}$
 $Say H_{1}(n)$
 $Say H_{2}(n)$
 $Say H_{2}(n)$

From above figure Power spectral density of input

S. In) # N. WHO

SY, (a) = 1H, (a) P S. (a)

 $SY_1(a) = 4N_2 WHz$ ('.' | $H_1(a)$ |² = 4) Again from above figure

 $SY_{2}(\alpha) = |H_{2}(\alpha)|^{2} \cdot SY_{1}(\alpha)$

SY2 (0) = 4 N2 WOIZ, - B 5 00 5 B Now, output noise power

$$= \int_{-3}^{5} SY_2(\alpha) d\alpha$$

=
$$8 N_0 B watt
wen figure
 $\int_{-\infty}^{\infty} p(v) dv = 1$$$

73. (C)







$$\label{eq:prod} \begin{array}{ll} \rho \left\{ v \right\} = \frac{k}{4} \cdot v \\ \\ \rho \left\{ v \right\} = \frac{1}{8} \times v \end{array}$$

Now, mean square value = $\int_{-\infty}^{\infty} v^2 p(v) dv$

75. (8)

(D) We know that
$$\begin{array}{c} Z_0 = \sqrt{Z_{DC} \times Z_{RC}} \\ \text{where } Z_0 = k \text{ hereactaristic impedance} \\ Z_{DC} = open circuit impedance \\ Z_{DC} = whent circuit impedance \\ given, \quad Z_0 = 10 \\ Z_{DC} = 100 + / 150 \\ Z_{DC} = Z_{RC} \text{ (when transmission line is} \end{array}$$

$$I_{058} = 10 \text{ mA}$$

 $V_{\mu} = -8 \text{ V}$
20 V



and	$Z_0 = R_d \ r_d$	
or	Z ₀ = 2 kΩ 20 kΩ	2
or	$Z_0 = \frac{20}{11} k\Omega$	

P2. (A) We know that

(A) We	know that
	$i_{D} = i_{DRR} \left(1 - \frac{V_{DS}}{V_{P}}\right)^{2}$
Here	V08 = -2 V
Nos.	$l_0 = 10 \text{ mA} \left[1 - \left(\frac{-2}{-8} \right) \right]^2$
or	$t_D = 10 \times \frac{9}{16} mA$
or	1p = 5-625 mA
and	V _{D5} = V _{DD} -I _D R ₀
or	Vps = 20-5625×10-3×2×103
or	V _{DS} = 20-11-250
or	V _{D5} = 8-75 V
(C)	Transconductance, g _w = 3/3 mS
and	Voltage gain, Ay = - ge Ro
	$= -3.3 \text{ mS} \times 2 \text{ k}\Omega$
	6 6
or	A = -6
a. (A) Th	e given program starts at location 0100 H
LOI SF	OOFF
DOM	0701
	dVLA, 20 H ← Data 20 H is transferred into A
	SUB M - When SUB M is encountered, PC
	reaches 0100 H
b. (C)	
	0H +- 20 H = 00100000
AD	ID M 40 H = 01000000
	01103000 + OR ing
	6 0 = 60H

Therefore, the result in the accumulator after the last instruction is executed is 60 H.

82a. (D) Given open loop transfer function with unity feedback

$$G(s) = \frac{3e^{-2s}}{s(s+2)}$$

Gain crossover frequency

$$\frac{3e^{2it}}{|s|(s+2)|} = 1$$
where, $|e^{-2it}| = \cos 2it - j\sin i$

$$= 1$$

$$\left|\frac{3 \times 1}{|itt} |s+2|\right| = 1$$

$$\begin{array}{c} x & \left\lfloor \frac{1}{2} x^{2} - \frac{1}{2} y \right\rfloor + 1 & \text{Treaters}, \quad \left\lfloor \frac{1}{2} + \frac{1}{2} y \right\rfloor \\ x & \left\lfloor \frac{1}{2} x^{2} + \frac{1}{2} y \right\rfloor + 1 & \text{Treaters}, \quad \left\lfloor \frac{1}{2} + \frac{1}{2} y \right\rfloor \\ x & x & x^{2} + \frac{1}{2} \\ x & y & x^{2} + \frac{1}{2} \\ x & x^{2} + \frac{1}$$



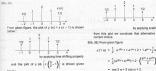
82

Since given that the three regions are divided into equi-probable region

05 = 0-6 Z_R + 30 = Z_R - 50 80 = 0.4 ZR $Z_{R} = \frac{80}{0.4} = 200 \Omega$ (C) Just celculated in solution Q. 84. (a)

or

ZR = 50 ZH + 50



 $y\left(1\,w\right) \;=\; \frac{1}{2} \cdot e^{-j2u} + 1.e^{-ju} + 2 + 1.e^{kt} + \frac{1}{2}e^{j2w}$

 $=\frac{1}{2}(a^{(2\alpha)}+a^{-(2\alpha)})+2\cdot\left(\frac{a^{(\alpha)}+a^{-(\alpha)}}{2}\right)+2$ = cos 2 a + 2 cos a + 2.